

2SC5849

Silicon NPN Epitaxial
VHF/UHF wide band amplifier

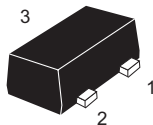
REJ03G0759-0100
(Previous ADE-208-1469)
Rev.1.00
Aug.10.2005

Features

Super compact package: MFPAK (1.4 x 0.8 x 0.59 mm)

Outline

RENESAS Package code: PUSF0003ZA-A
(Package name: MFPAK[®])



- 1. Emitter
- 2. Base
- 3. Collector

Note: Marking is "WY-".

*MFPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

(Ta = 25°C)

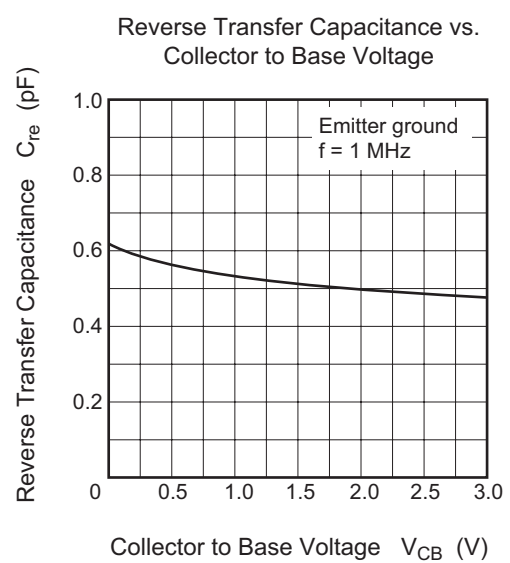
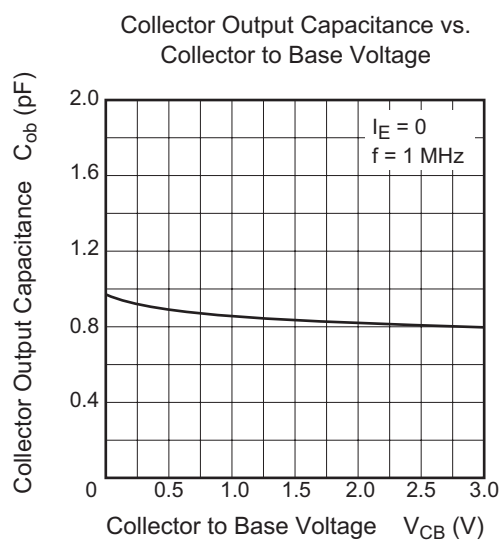
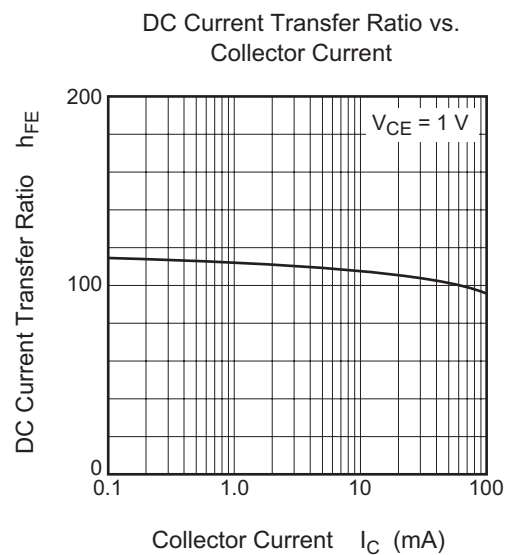
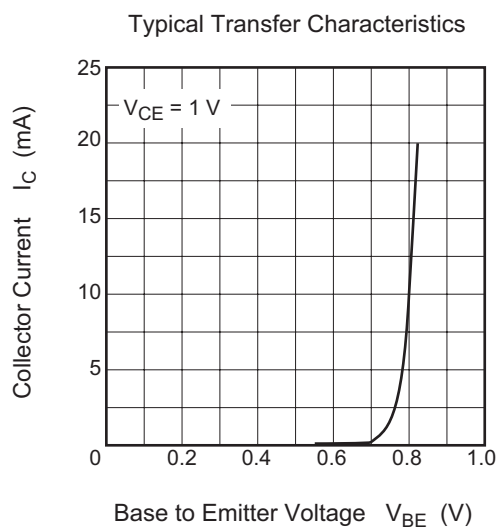
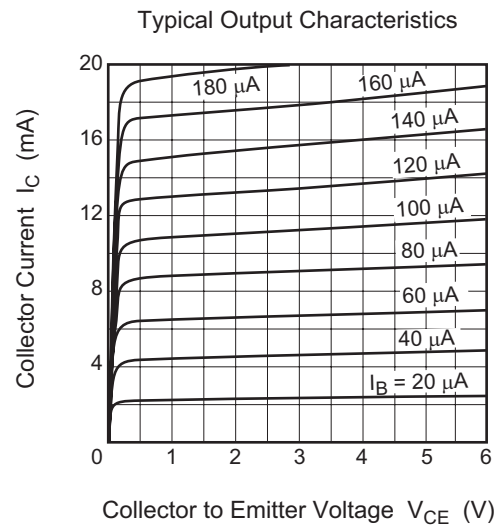
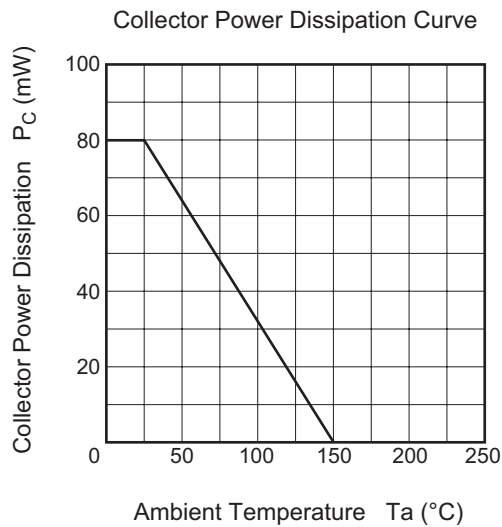
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V_{CEO}	6.0	V
Emitter to base voltage	V_{EBO}	1.5	V
Collector current	I_C	80	mA
Collector power dissipation	P_C	80	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to 150	°C

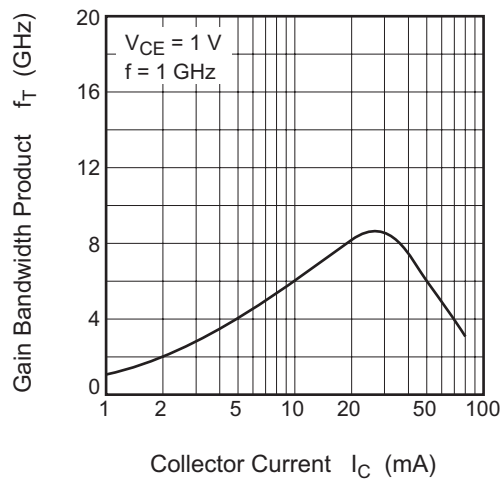
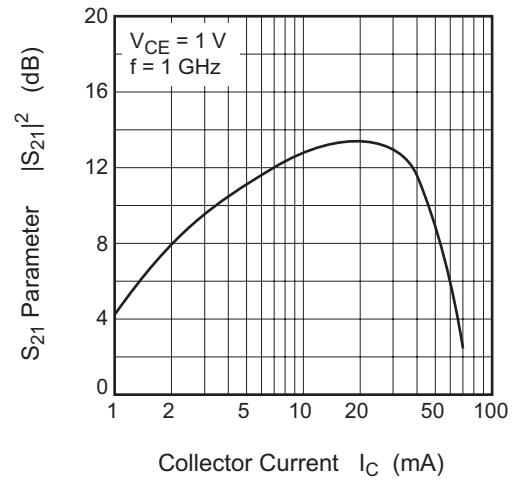
Electrical Characteristics

(Ta = 25°C)

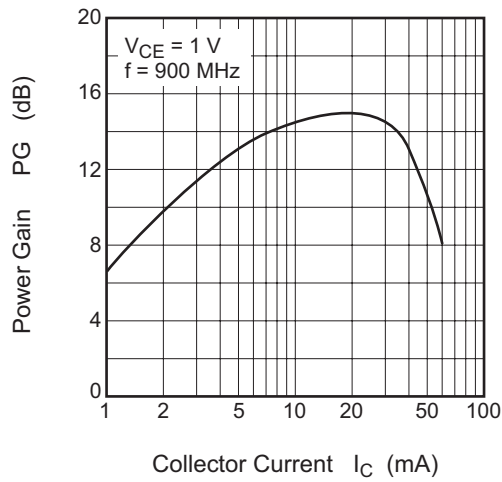
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	—	—	V	$I_C = 10\ \mu A, I_E = 0$
Collector cutoff current	I_{CBO}	—	—	0.1	μA	$V_{CB} = 15\ V, I_E = 0$
Collector cutoff current	I_{CEO}	—	—	0.1	μA	$V_{CE} = 6.0\ V, R_{BE} = \infty$
Emitter cutoff current	I_{EBO}	—	—	0.1	μA	$V_{EB} = 1.5\ V, I_C = 0$
DC current transfer ratio	h_{FE}	90	110	140		$V_{CE} = 1\ V, I_C = 5\ mA$
Reverse transfer capacitance	C_{re}	—	0.5	—	pF	$V_{CE} = 1\ V$, Emitter ground, $f = 1\ MHz$
Collector output capacitance	C_{ob}	—	0.85	1.15	pF	$V_{CB} = 1\ V, I_E = 0, f = 1\ MHz$
Gain bandwidth product	$f_T(1)$	1.0	4.0	—	GHz	$V_{CE} = 1\ V, I_C = 5\ mA$
Gain bandwidth product	$f_T(2)$	—	9.0	—	GHz	$V_{CE} = 1\ V, I_C = 30\ mA$
Power gain	PG	10	13	—	dB	$V_{CE} = 1\ V, I_C = 5\ mA$, $f = 900\ MHz$
Noise figure	NF	—	1.1	1.8	dB	$V_{CE} = 1\ V, I_C = 5\ mA$, $f = 900\ MHz$

Main Characteristics

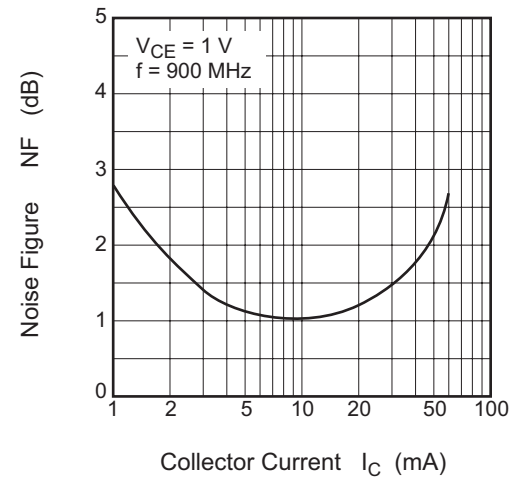


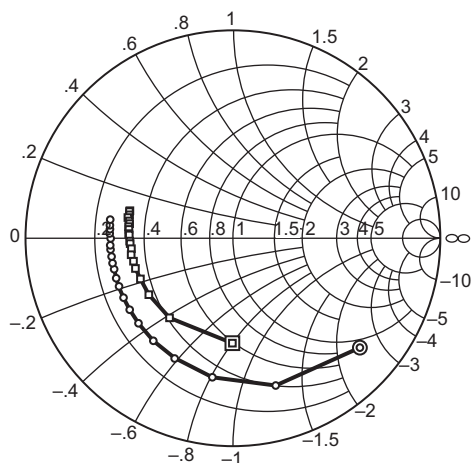
Gain Bandwidth Product vs.
Collector Current S_{21} Parameter vs. Collector Current

Power Gain vs. Collector Current



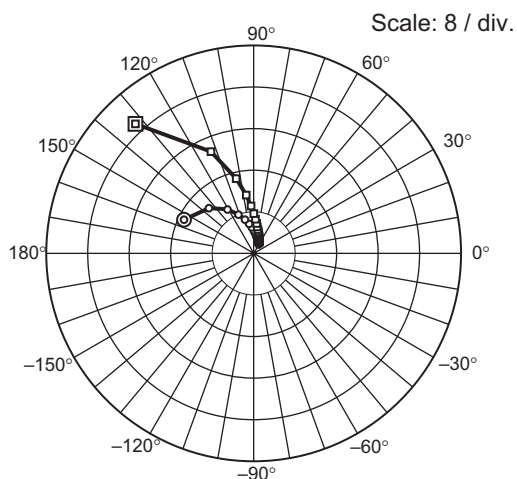
Noise Figure vs. Collector Current



S₁₁ Parameter vs. Frequency

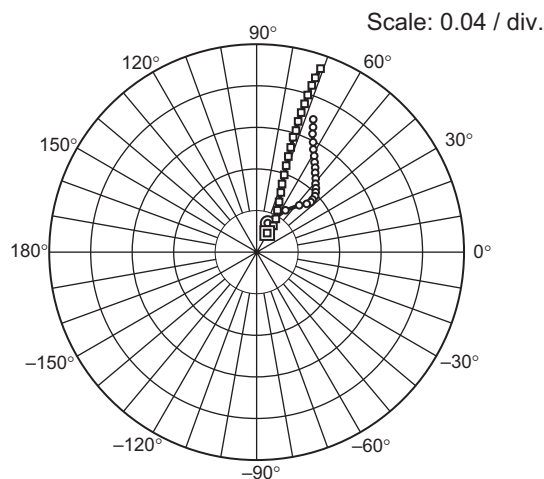
Test conditions: $V_{CE} = 1\text{ V}$, $Z_O = 50\ \Omega$
100 to 2000 MHz (100 MHz step)

⊙—○ ($I_C = 5\text{ mA}$)
⊠—□ ($I_C = 20\text{ mA}$)

S₂₁ Parameter vs. Frequency

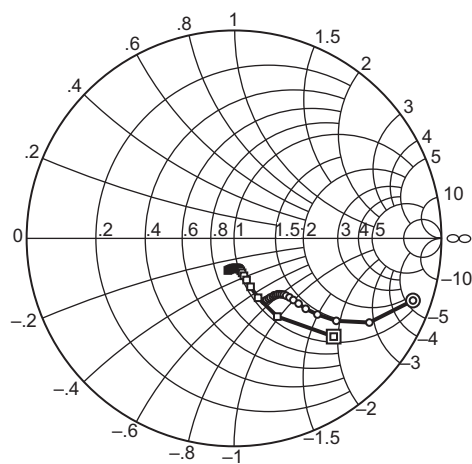
Test conditions: $V_{CE} = 1\text{ V}$, $Z_O = 50\ \Omega$
100 to 2000 MHz (100 MHz step)

⊙—○ ($I_C = 5\text{ mA}$)
⊠—□ ($I_C = 20\text{ mA}$)

S₁₂ Parameter vs. Frequency

Test conditions: $V_{CE} = 1\text{ V}$, $Z_O = 50\ \Omega$
100 to 2000 MHz (100 MHz step)

⊙—○ ($I_C = 5\text{ mA}$)
⊠—□ ($I_C = 20\text{ mA}$)

S₂₂ Parameter vs. Frequency

Test conditions: $V_{CE} = 1\text{ V}$, $Z_O = 50\ \Omega$
100 to 2000 MHz (100 MHz step)

⊙—○ ($I_C = 5\text{ mA}$)
⊠—□ ($I_C = 20\text{ mA}$)

S Parameter

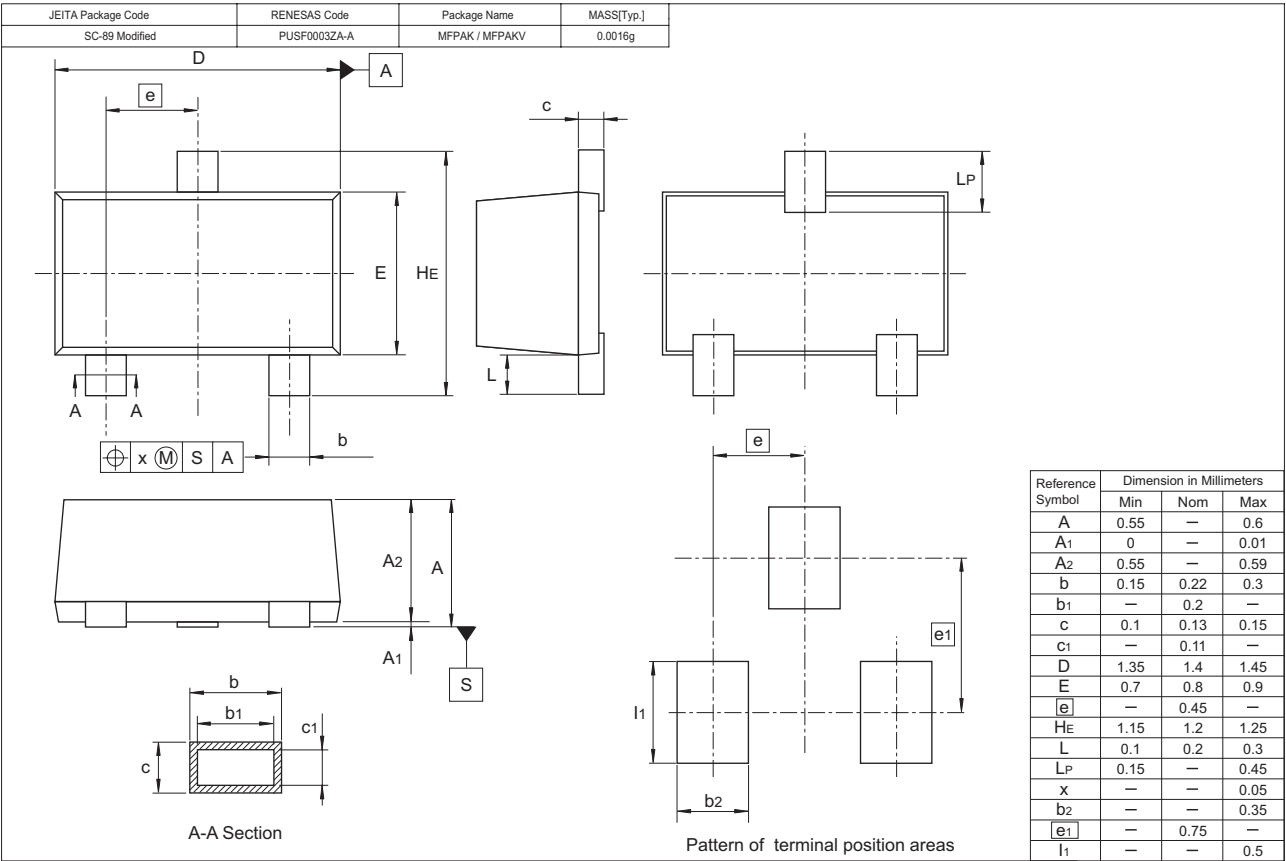
(V_{CE} = 1 V, I_C = 5 mA, Z_O = 50 Ω)

f (MHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.807	-40.6	14.95	154.2	0.030	69.3	0.913	-19.1
200	0.737	-73.7	12.30	135.0	0.049	55.5	0.768	-31.8
300	0.675	-98.4	9.86	121.2	0.061	47.8	0.633	-38.8
400	0.642	-115.9	8.03	111.9	0.067	44.0	0.544	-42.3
500	0.624	-127.9	6.72	105.0	0.071	42.8	0.484	-44.4
600	0.611	-138.1	5.75	99.4	0.074	43.2	0.442	-45.2
700	0.604	-145.4	5.02	95.0	0.078	43.8	0.412	-46.0
800	0.599	-151.6	4.45	90.9	0.081	45.4	0.390	-46.7
900	0.595	-157.2	3.98	87.6	0.084	47.2	0.373	-47.6
1000	0.594	-161.2	3.62	84.5	0.087	49.3	0.362	-48.4
1100	0.591	-165.5	3.33	81.8	0.091	51.3	0.354	-49.5
1200	0.592	-168.4	3.06	79.0	0.095	53.6	0.347	-50.7
1300	0.591	-171.5	2.86	76.4	0.099	55.3	0.341	-52.0
1400	0.592	-174.8	2.66	74.1	0.103	57.2	0.340	-53.5
1500	0.592	-176.8	2.51	72.0	0.108	59.1	0.335	-54.8
1600	0.589	-180.0	2.35	69.7	0.113	61.1	0.337	-56.3
1700	0.594	177.7	2.23	67.8	0.119	62.8	0.334	-58.3
1800	0.594	175.7	2.13	65.7	0.126	64.7	0.335	-60.0
1900	0.596	173.9	2.03	63.7	0.132	65.7	0.335	-62.0
2000	0.598	171.3	1.94	61.9	0.139	66.9	0.335	-64.0

(V_{CE} = 1 V, I_C = 20 mA, Z_O = 50 Ω)

f (MHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.504	-90.3	33.79	132.5	0.021	61.4	0.674	-44.5
200	0.490	-128.6	21.25	112.9	0.030	57.6	0.431	-61.0
300	0.488	-146.2	14.78	103.3	0.037	60.2	0.309	-67.9
400	0.487	-156.3	11.31	97.4	0.045	63.7	0.247	-71.1
500	0.492	-162.8	9.13	93.3	0.053	66.0	0.210	-73.2
600	0.492	-167.0	7.65	90.0	0.062	68.0	0.187	-75.1
700	0.497	-170.8	6.58	87.2	0.070	69.6	0.171	-76.7
800	0.492	-174.1	5.78	84.4	0.079	70.4	0.160	-78.2
900	0.496	-177.0	5.13	82.6	0.088	71.2	0.152	-79.9
1000	0.498	-178.4	4.65	80.2	0.097	71.7	0.147	-81.4
1100	0.500	178.2	4.24	78.3	0.106	72.0	0.145	-83.2
1200	0.503	177.5	3.90	76.1	0.116	72.4	0.143	-85.1
1300	0.503	175.2	3.63	74.3	0.123	72.1	0.143	-87.2
1400	0.506	173.7	3.38	72.6	0.132	72.4	0.144	-88.8
1500	0.503	172.0	3.17	70.9	0.141	72.3	0.144	-91.2
1600	0.507	170.6	2.99	69.4	0.150	72.1	0.146	-92.8
1700	0.516	168.9	2.82	67.7	0.159	72.0	0.148	-95.0
1800	0.511	167.3	2.68	66.0	0.169	71.7	0.151	-97.0
1900	0.515	165.6	2.56	64.6	0.177	71.4	0.154	-99.0
2000	0.514	165.1	2.45	63.0	0.187	70.8	0.158	-100.8

Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC5849WY-TR-E	9000	φ 178 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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